

NEC's L, S-BAND 4W SPDT SWITCH

UPG2009TB

FEATURES

· LOW INSERTION LOSS:

0.25 dB TYP. @ Vcont1/2 = 2.8 V/0 V, f = 1.0 GHz 0.30 dB TYP. @ Vcont1/2 = 2.8 V/0 V, f = 2.0 GHz

· HIGH ISOLATION:

28 dB TYP. @ $V_{cont1/2} = 2.8 \text{ V/O V}$, f = 2.0 GHz

POWER HANDLING:

Pin (0.1dB) = 34 dBm TYP. @ Vcont1/2 = 2.8 V/0 V, f = 1.0 GHzPin (1.0dB) = 36 dBm TYP. @ Vcont1/2 = 2.8 V/0 V, f = 1.0 GHz

• 6-PIN SUPER MINIMOLD PACKAGE ($2.0 \times 1.25 \times 0.9$ mm)

DESCRIPTION

The UPG2009TB is a L, S-band SPDT (Single Pole Double Throw) GaAs FET switch for digital cellular or cordless telephone application. The device can operate from 500 MHz to 2.5 GHz, with low insertion loss and high isolation.

APPLICATIONS

- · L-band digital cellular or cordless telephone
- BluetoothTM, W-LAN and WLL
- · Short Range Wireless

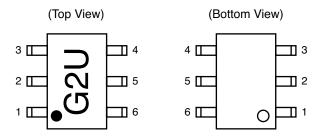
ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
UPG2009TB-E3	6-pin super minimold	G2U	Embossed tape 8 mm wide Pin 1, 2, 3 face the perforation side of the tape Qty 3 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office. Part number for sample order: UPG2009TB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

PIN CONNECTIONS



Pin No.	Pin Name
1	OUT1
2	GND
3	OUT2
4	VCont2
5	IN
6	VCont1

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Control Voltage 1, 2	Vcont1, 2	-6.0 to +6.0 Note1	V
Input Power	Pin	+36	dBm
Total Power Dissipation	P _{tot}	0.15	W
Operating Ambient Temperature	TA	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note $| V_{cont1} - V_{cont2} | \le 6.0 \text{ V}$

RECOMMENDED OPERATING RANGE (TA = 25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Control Voltage (High)	Vcont (H)	+2.7	+2.8	+3.0	٧
Control Voltage (Low)	V _{cont (L)}	-0.2	0	+0.2	٧

ELECTRICAL CHARACTERISTICS

(TA = +25°C, Vcont1 = 2.8 V, Vcont2 = 0 V or Vcont1 = 0 V, Vcont2 = 2.8, $Z_0 = 50 \Omega$, off chip DC blocking capacitors value; 56 pF, unless otherwise specified)

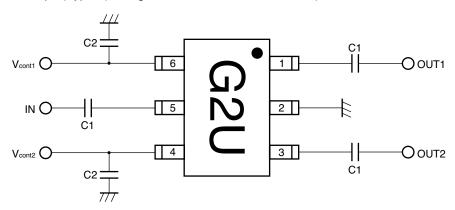
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss	Lins	f = 0.5 to 1.0 GHz	-	0.25	0.45	dB
		f = 2.0 GHz	-	0.30	0.50	dB
		f = 2.5 GHz	-	0.40	_	dB
Isolation	ISL	f = 0.5 to 2.0 GHz	24	28	_	dB
		f = 2.5 GHz	-	25	_	dB
Input Return Loss	RLin	f = 0.5 to 2.5 GHz	15	20	_	dB
Output Return Loss	RLout	f = 0.5 to 2.5 GHz	15	20	_	dB
Input Power at 0.1 dB	Pin(0.1 dB)	f = 1.0 GHz,	32.5	34	_	dBm
Compression Point Note		V _{cont} = 2.8 V/0 V				
2nd Harmonics	2f0	f = 1.0 GHz, V _{cont} = 2.8 V/0 V,	65	75	-	dBc
		Pin = 30.5 dBm				
3rd Harmonics	3f0	f = 1.0 GHz, V _{cont} = 2.8 V/0 V,	65	75	-	dBc
		P _{in} = 30.5 dBm				
Switching Speed	tsw		-	150	-	ns
Control Current	Icont	V _{cont} = 2.8 V/0 V, RF Non	-	1	50	μΑ

Note Pin (0.1 dB) is the measured input power level when the insertion loss increases 0.1 dB more than that of linear range. All other characteristics are measured in linear range.

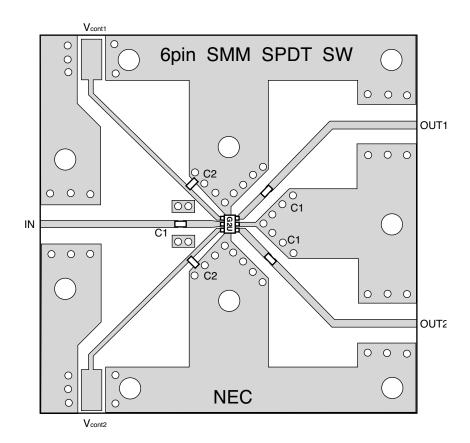
Caution It is necessary to use DC blocking capacitors with the device.

The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system. The range of recommended DC blocking capacitor value is less than 100 pF.

EVALUATION CIRCUIT (Vcont1 = 2.8 V, Vcont2 = 0 V or Vcont2 = 0 V, Vcont1 = 2.8 V, off chip DC blocking capacitors value C1 = 56 pF, C2 = 1 000 pF (Bypass), using NEC standard evaluation board)



EVALUATION BOARD



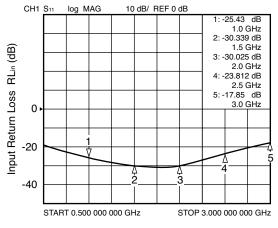
TRUTH TABLE

Vcont1	Vcont2	IN-OUT1	IN-OUT2
Low	High	OFF	ON
High	Low	ON	OFF

TYPICAL CHARACTERISTICS

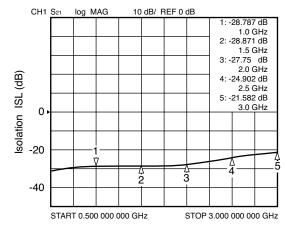
(TA = $+25^{\circ}$ C Vcont1/2 = 2.8 V/0 V, Pin = 0 dBm, OUT2 side is 50 Ω termination)

INPUT RETURN LOSS vs. FREQUENCY



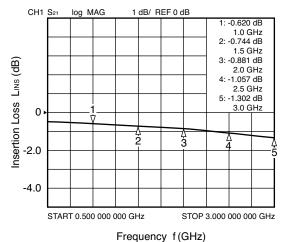
Frequency f(GHz)

ISOLATION vs. FEQUENCY

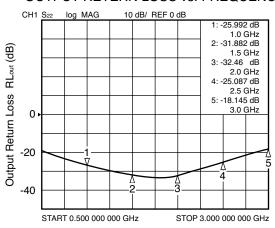


Frequency f(GHz)

INSERTION LOSS vs. FREQUENCY



OUTPUT RETERN LOSS vs. FREQUENCY



Frequency f(GHz)

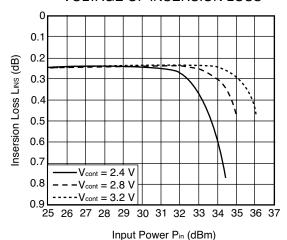
Caution These characteristics values include the losses of the NEC evaluation board.

Remark The graphs indicate nominal characteristics.

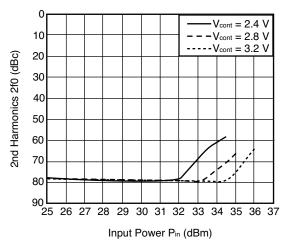
TYPICAL CHARACTERISTICS

(f = 2 GHz, OUT2 side is 50 Ω termination)

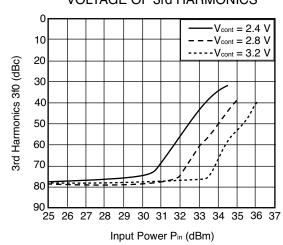
RELATION BETWEEN CONTROL VOLTAGE OF INSERSION LOSS



RELATION BETWEEN CONTROL VOLTAGE OF 2nd HARMONICS



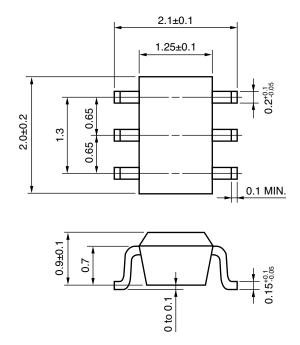
RELATION BETWEEN CONTROL VOLTAGE OF 3rd HARMONICS



Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
VPS	Peak temperature (package surface temperature)	: 215°C or below	VP215
	Time at temperature of 200°C or higher	: 25 to 40 seconds	
	Preheating time at 120 to 150°C	: 30 to 60 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Wave Soldering	Peak temperature (molten solder temperature)	: 260°C or below	WS260
	Time at peak temperature	: 10 seconds or less	
	Preheating temperature (package surface temperature)	: 120°C or below	
	Maximum number of flow processes	: 1 time	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (pin temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

Caution Do not use different soldering methods together (except for partial heating).

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these prod be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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